

# L, S Band SPDT GaAs MMIC Switch

## **UPG154TB**

## **FEATURES**

#### LOW INSERTION LOSS:

LINS = 0.65 dB TYP at VCONT = +3.0 V/0 V, VDD = +3 V, CX = 2 pF, f = 2 GHz

## • HIGH POWER SWITCHING:

Pin (1 dB) = +30 dBm TYP at VCONT = +3.0 V/0 V, VDD = +3 V, Cx = 2 pF, f = 2 GHz

## • SMALL 6 PIN MINI-MOLD PACKAGE:

Size: 2.0 x 1.25 x 0.9 mm

## **DESCRIPTION**

The UPG154TB is an L-band SPDT (Single Pole Double Throw) GaAs FET switch for digital cellular or cordless telephone application. The device can operate from 100 MHz to 2.5 GHz with low insertion loss. This device is housed in an original 6 pin super mini-mold package similar to SOT363.

NEC's stringent quality assurance and test procedures assure the highest reliability and performance.

## **APPLICATION**

- L, S-BAND DIGITAL CELLULAR OR CORDLESS TELEPHONE
- PCS, WLAN AND WLL APPLICATIONS

## **ELECTRICAL CHARACTERISTICS**

(Unless otherwise specified, TA = 25°C, VCONT1 = 3 V, VCONT2 = 0 V or VCONT1 = 0 V, VCONT2 = 3 V; off chip DC blocking capacitor value, 51 pF)

PART NUMBER PACKAGE OUTLINE			UPG154TB \$06			
SYMBOLS	PARAMETERS AND CONDITIONS		UNITS	MIN	TYP	MAX
Lins	Insertion Loss	f = 0.1 – 1 GHz, Cx = 12 pF f = 2.0 GHz, Cx = 2 pF	dB		0.3 0.65	0.65 0.90
IsL	Isolation	f = 1 GHz, Cx = 12 pF f = 1.5 GHz, Cx = 4.5 pF f = 2 GHz, Cx = 2 pF	dB	20 18	24 22 21	
RLin	Input Return Loss	f = 0.1 - 2 GHz, Cx = 2 pF	dB	11	15	
RLout	Output Return Loss	f = 0.1 - 2 GHz, Cx = 2 pF	dB	11	15	
PIN(1 dB)	Input Power 1 dB Compression Point, f = 2 GHz, Cx = 2 pF		dBm	27	30	
PIN(0.1 dB)	Input Power 0.1 dB Compression Point, f = 2 GHz, Cx = 2 pF		dBm		26.5	
tsw	Switching Speed		ns		30	
ICONT	Control Current at Vcont = 3 V/0 V, no RF signal		μΑ		2	10

### Note:

- 1. When the UPG154TB is used, it is necessary to use DC blocking capacitors for the RF input and RF output. The value of DC blocking capacitors should be chosen to accommodate the frequency of operation. The range of recommended DC blocking capacitor value is less than 100 pF.
- 2. The distance between IC's GND pin and ground pattern of substrate should be as short as possible to avoid parasitics.

\_California Eastern Laboratories

# ABSOLUTE MAXIMUM RATINGS<sup>1</sup> (TA = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
VCONT1, 2	Control Voltage 1, 2 <sup>2</sup>	V	-6 to +6
VDD	Supply Voltage	V	5
Pin	Input Power	dBm	+31
Ртот	Total Power Dissipation <sup>3</sup>	W	0.15
TA	Operating Temperature	°C	-45 to +85
Тѕтс	Storage Temperature	°C	-55 to +150

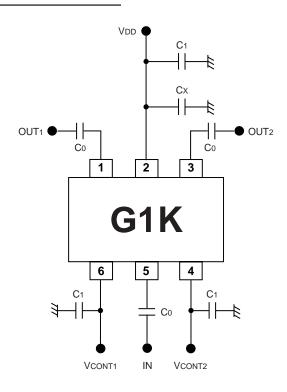
#### Notes:

- Operation in excess of any one of these conditions may result in permanent damage.
- 2.  $2.5 \text{ V} \leq \text{I VCONT1} \text{VCONT2} \text{ I} \leq 6 \text{ V}$
- 3. Mounted on a 50 x 50 x 1.6 mm double copper clad epoxy glass PWB, TA = +85 °C.

## **RECOMMENDED OPERATING CONDITIONS** (TA = 25°C)

			UPG154TB		
SYMBOL	PARAMETER	UNITS	MIN	TYP	MAX
VCONT	Control Voltage (High)	V	+2.5	+3.0	+5.3
VCONT	Control Voltage (Low)	V	-0.2	0	+0.2
VDD	Supply Voltage	V	+2.5	VCONT(H)	VCONT(H)+0.3

## TEST CIRCUIT<sup>1</sup>



## Note:

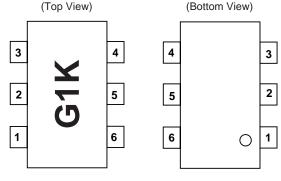
- 1. (TA = 25°C, VCONT1 = +3 V, VCONT2 = 0 V or VCONT1 = 0 V, VCONT2 = +3 V, VDD = +3 V, f = 2 GHz. Off chip DC blocking capacitors value: C0 = 51 pF, C1 = 1000 pF (Bypass: Select a suitable value for your application, especially concerning switching speed). Cx = 2 pF (In case of 2 GHz).
- 2. For optimum isloation, Cx should be placed as close as possible to pin 2.

## TRUTH TABLE OF SWITCHING BY CONDITION OF CONTROL VOLTAGE

		Vcont1			
		Vcont(h)	VCONT(L)		
VCONT2	Vcont(H)	●— OUT1 ●— OUT2	OUT1 OUT2		
	Vcont(L)	●— OUT1 ●— OUT2	IN — OUT1		

## PIN CONNECTION DIAGRAM

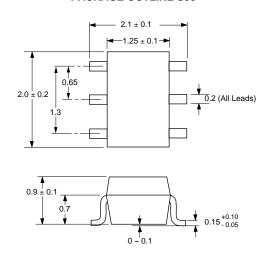
PIN NO.	CONNECTION
1	OUT1
2	Vdd
3	OUT2
4	VCONT2
5	IN
6	VCONT1



UPG154TB

## **OUTLINE DIMENSIONS** (Units in mm)

## **PACKAGE OUTLINE S06**



## Note:

Embossed Tape, 8 mm wide,

Pins 1, 2, 3 face tape perforation side.

# ORDERING INFORMATION

PART NUMBER	QUANTITY	
UPG154TB-E3	3 kpcs/Reel	

All dimensions are typical unless otherwise specified.

### Life Support Applications

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